

(Ga,Mn)As

$T_g = 250^\circ\text{C}$

500 nm

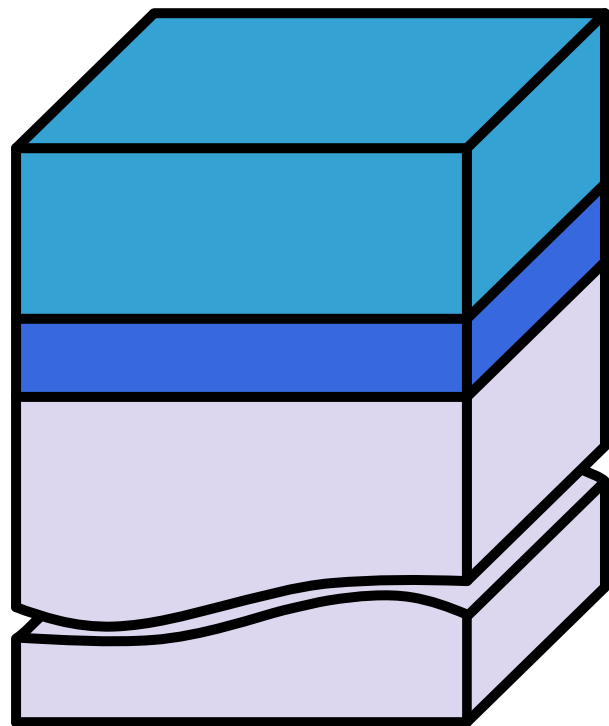
Mn: 1 ÷ 5%

buffer GaAs

$T_g = 600^\circ\text{C}$

100 nm

GaAs (001)



FM1 ÷ 6 (MBE)

GaAs:Mn

$T_g = 540^\circ\text{C}$

1000 nm

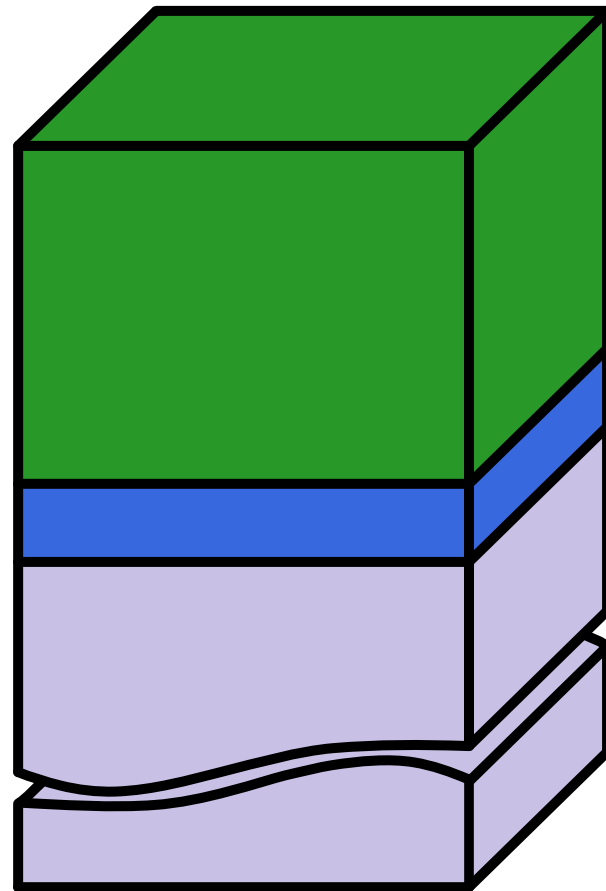
Mn:  $3 \times 10^{17} \text{ cm}^{-3}$

buffer GaAs

$T_g = 600^\circ\text{C}$

100 nm

GaAs (001)



R (MBE)